PBSS4350T-Q

50 V; 3 A NPN low VCEsat transistor

10 May 2022 **Product data sheet**

1. General description

NPN low V_{CEsat} transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5350T-Q

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat} and corresponding low R_{CEsat}
- High collector current capability
- High collector current gain
- Improved efficiency due to reduced heat generation.
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Power management applications
- Low and medium power DC/DC converters
- Supply line switching
- Battery chargers
- Linear voltage regulation with low voltage drop-out (LDO).

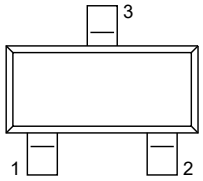
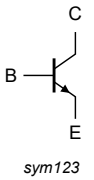
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	50	V
I_C	collector current			-	-	2	A
I_{CM}	peak collector current	single pulse; $t_p \leq$ 1 ms		-	-	5	A
R_{CEsat}	collector-emitter saturation resistance	I_C = 2 A; I_B = 200 mA; pulsed; $t_p \leq$ 300 µs; $\delta \leq$ 0.02; T_{amb} = 25 °C		-	100	130	mΩ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base	 SOT23	 sym123
2	E	emitter		
3	C	collector		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS4350T-Q	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS4350T-Q	ZC%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	5	V
I_C	collector current			-	2	A
I_{CRM}	repetitive peak collector current	$\delta \leq 0.25$; $t_p \leq 100$ ms		-	3	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms		-	5	A
I_B	base current			-	0.5	A
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	300	mW
			[2]	-	480	mW
			[3]	-	540	mW
			[1] [4]	-	1.2	W
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-65	150	°C
T_{stg}	storage temperature			-65	150	°C

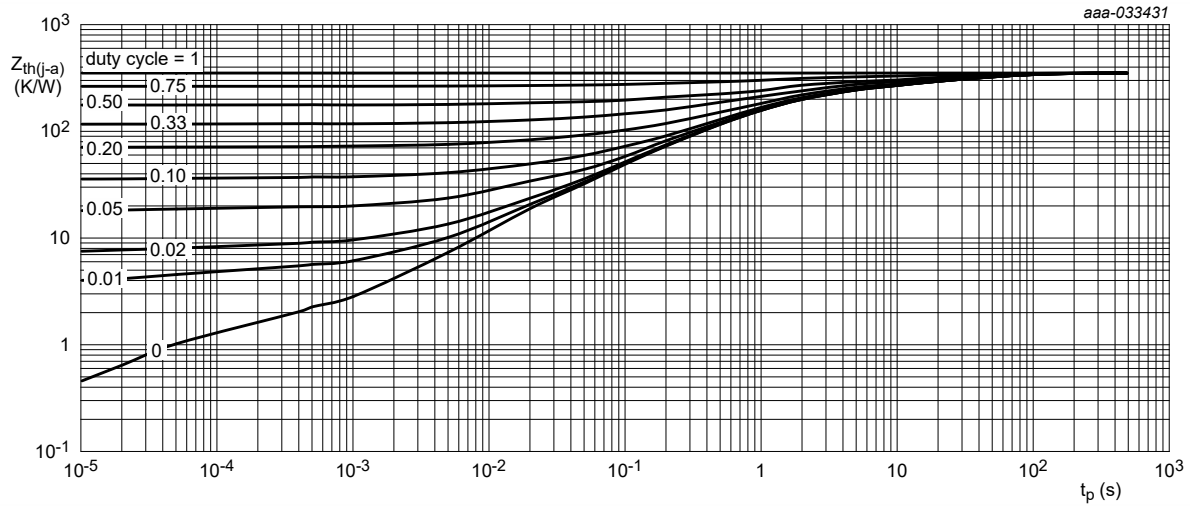
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm^2.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm^2.
[4] Operated under pulsed conditions: $t_p \leq 100$ ms; $\delta \leq 0.25$.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
			[2]	-	-	260	K/W
			[3]	-	-	230	K/W
			[1] [4]	-	-	104	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm^2.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm^2.
[4] Operated under pulsed conditions: $t_p \leq 100$ ms; $\delta \leq 0.25$.



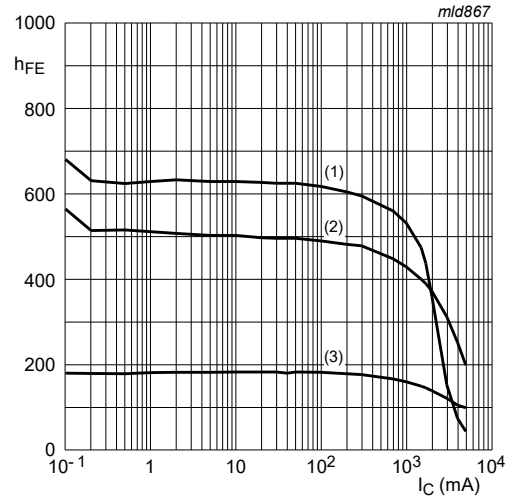
Mounted on FR4 PCB; standard footprint.

Fig. 1. Transient thermal impedance as a function of pulse duration; typical values

10. Characteristics

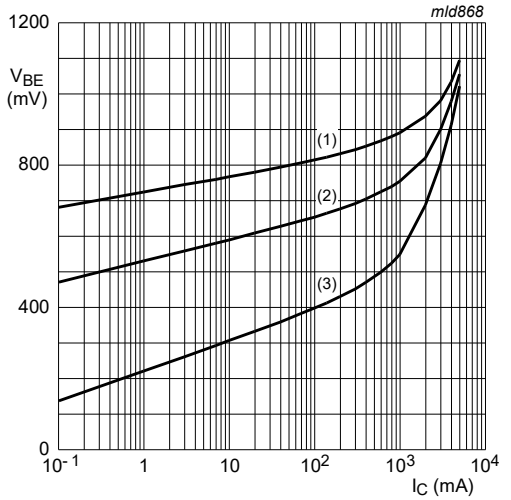
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I_C = 100 µA; I_E = 0 A; T_{amb} = 25 °C		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I_C = 10 mA; I_B = 0 A; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage (collector open)	I_E = 100 µA; I_C = 0 A; T_{amb} = 25 °C		5	-	-	V
I_{CBO}	collector-base cut-off current	V_{CB} = 50 V; I_E = 0 A; T_{amb} = 25 °C		-	-	100	nA
		V_{CB} = 50 V; I_E = 0 A; T_j = 150 °C		-	-	50	µA
I_{EBO}	emitter-base cut-off current	V_{EB} = 5 V; I_C = 0 A; T_{amb} = 25 °C		-	-	100	nA
h_{FE}	DC current gain	V_{CE} = 2 V; I_C = 100 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		300	-	-	
		V_{CE} = 2 V; I_C = 500 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		300	-	-	
		V_{CE} = 2 V; I_C = 1 A; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		300	-	-	
		V_{CE} = 2 V; I_C = 2 A; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		200	-	-	
		V_{CE} = 2 V; I_C = 3 A; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		100	-	-	
V_{CEsat}	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA; T_{amb} = 25 °C		-	-	80	mV
		I_C = 1 A; I_B = 50 mA; T_{amb} = 25 °C		-	-	160	mV
		I_C = 2 A; I_B = 100 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	280	mV
		I_C = 2 A; I_B = 200 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	260	mV
		I_C = 3 A; I_B = 300 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	370	mV
R_{CEsat}	collector-emitter saturation resistance	I_C = 2 A; I_B = 200 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	100	130	mΩ
V_{BEsat}	base-emitter saturation voltage	I_C = 2 A; I_B = 100 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	1.1	V
		I_C = 3 A; I_B = 300 mA; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	1.2	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I_C = 1 A; pulsed; $t_p \leq$ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	1.2	V
f_T	transition frequency	V_{CE} = 5 V; I_C = 100 mA; f = 100 MHz; T_{amb} = 25 °C		100	-	-	MHz
C_c	collector capacitance	V_{CB} = 10 V; I_E = 0 A; i_e = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	25	pF



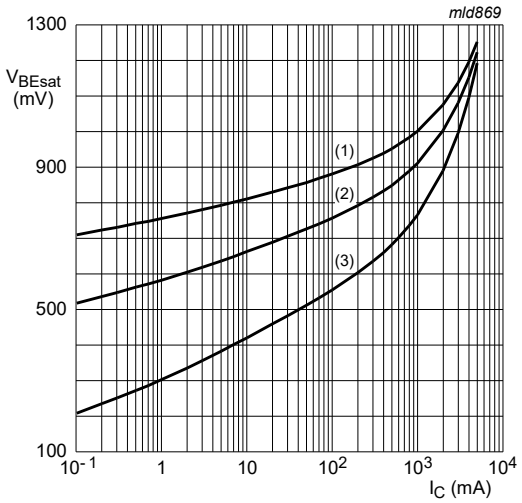
V_{CE} = 2 V
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 2. DC current gain as a function of collector current; typical values



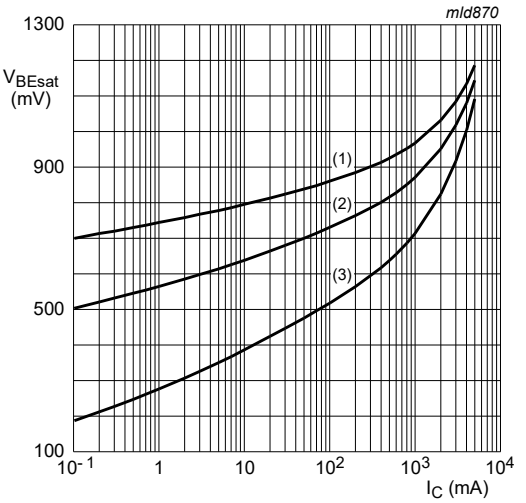
V_{CE} = 2 V
(1) T_{amb} = −55 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 150 °C

Fig. 3. Base-emitter voltage as a function of collector current; typical values



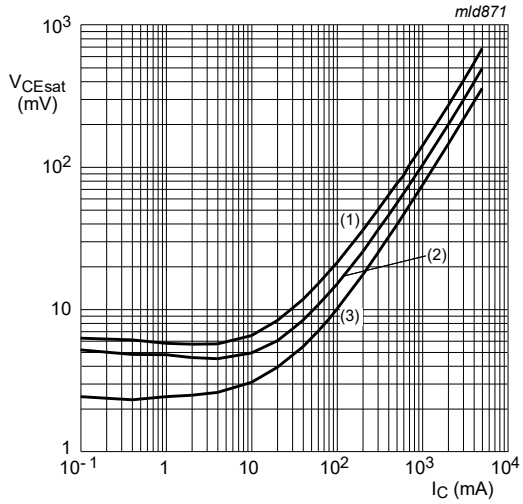
I_C/I_B = 10
(1) T_{amb} = −55 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 150 °C

Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values



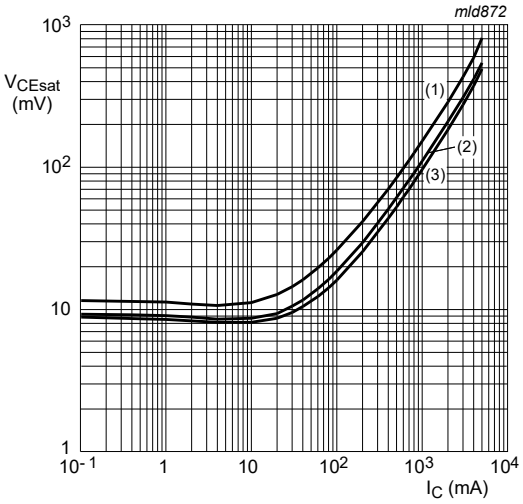
I_C/I_B = 20
(1) T_{amb} = −55 °C
(2) T_{amb}= 25 °C
(3) T_{amb} = 150 °C

Fig. 5. Base-emitter saturation voltage as a function of collector current; typical values



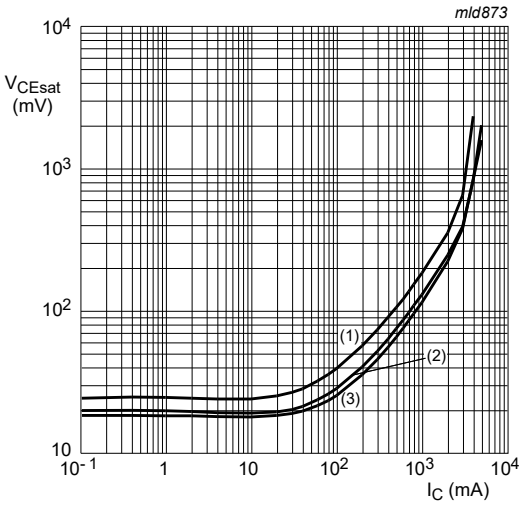
I_C/I_B = 10
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



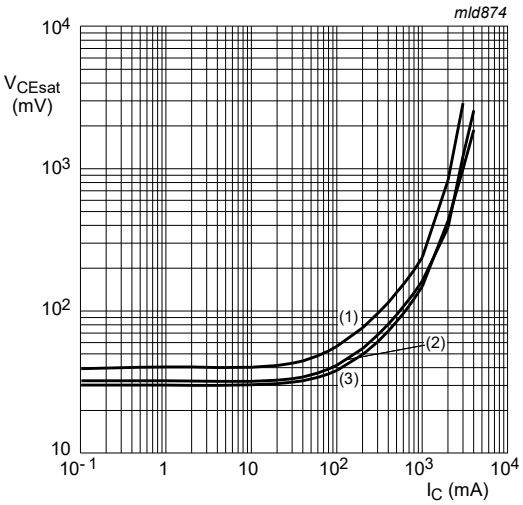
I_C/I_B = 20
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



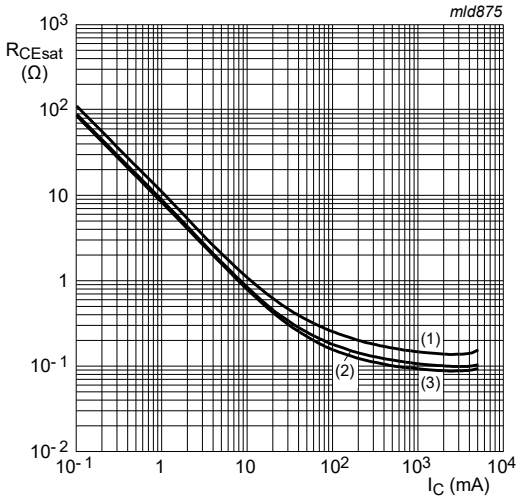
I_C/I_B = 50
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



I_C/I_B = 100
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values



I_C/I_B = 20
(1) T_{amb} = 150 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = −55 °C

Fig. 10. Equivalent on-resistance as a function of collector current; typical values

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

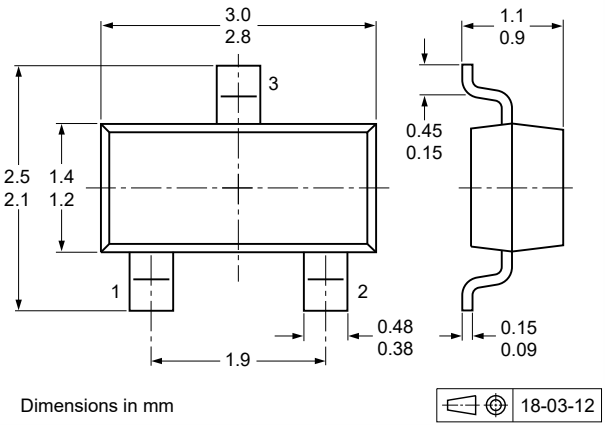


Fig. 11. Package outline SOT23

13. Soldering

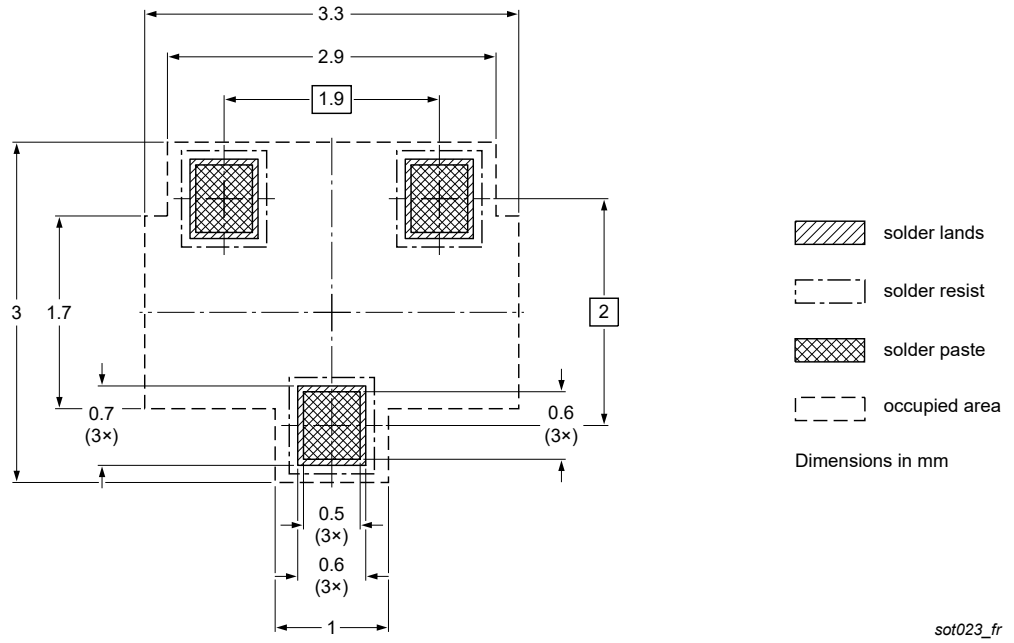


Fig. 12. Reflow soldering footprint for SOT23

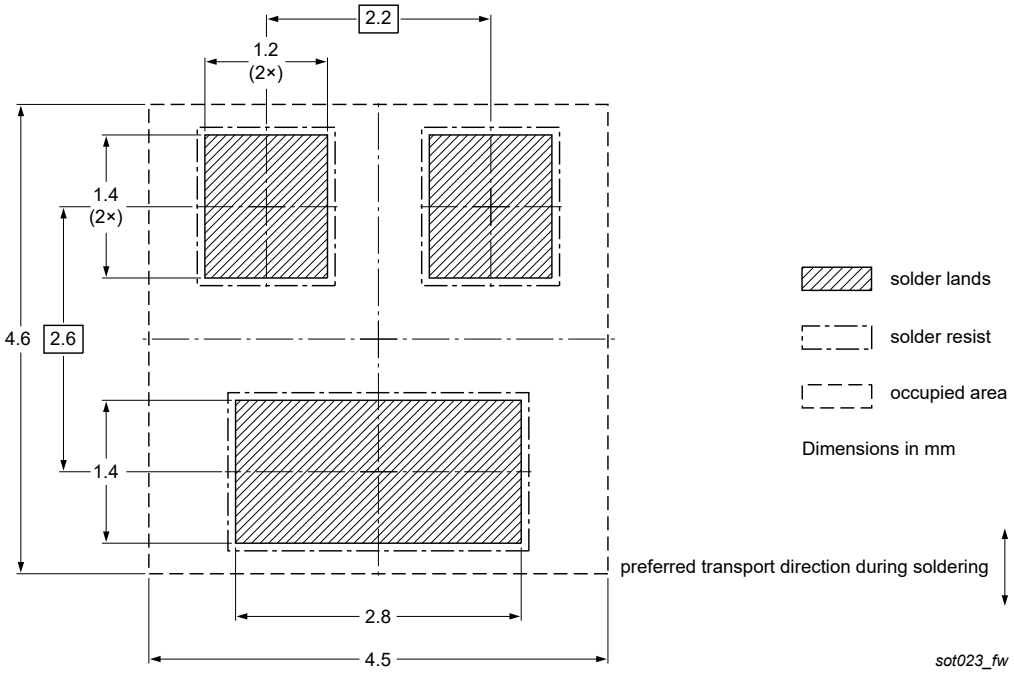


Fig. 13. Wave soldering footprint for SOT23

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4350T-Q v.1	20220510	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".
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